

Search update 9/14/04 JFZ (47P)

L Number	Hits	Search Text	DB	Time stamp
1	6	((("5306655") or ("5360655") or ("5612249") or ("5798550") or ("6015736") or ("5637514")).PN.	USPAT; US-PGPUB	2004/09/14 17:59
2	6	((("5306655") or ("5360758") or ("5612249") or ("5798550") or ("6015736") or ("5637514")).PN.	USPAT; US-PGPUB	2004/09/14 17:59
3	6	(US-5798550-\$ or US-6015736-\$ or US-5360758-\$ or US-5612249-\$ or US-5637514-\$ or US-5306655-\$).did.	USPAT	2004/09/14 18:39
4	7466	((257/288) or (257/296) or (257/321) or (257/344) or (257/368) or (257/401) or (257/408) or (257/410) or (257/411) or (257/412) or (257/413)).CCLS.	USPAT; US-PGPUB	2004/09/14 18:40
5	0	((257/288) or (257/296) or (257/321) or (257/344) or (257/368) or (257/401) or (257/408) or (257/410) or (257/411) or (257/412) or (257/413)).CCLS.) and silicon adj oxide adj passivation adj (layer film) and silicon adj nitride adj spacer and gate adj oxide.ti,ab,clm. and "bird's beak"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 18:42
6	0	((257/288) or (257/296) or (257/321) or (257/344) or (257/368) or (257/401) or (257/408) or (257/410) or (257/411) or (257/412) or (257/413)).CCLS.) and silicon adj oxide near8 passivation adj (layer film) and silicon adj nitride near8 spacer and gate adj oxide.ti,ab,clm. and "bird's beak"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 18:42
-	5	272,968.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 16:45
-	1	"5612249".PN.	USPAT	2002/05/22 14:58
-	1	"5637514".PN.	USPAT	2002/05/22 14:59
-	1	"5798550".PN.	USPAT	2002/05/22 14:59
-	1	"6015736".PN.	USPAT	2002/05/22 15:00
-	3	("5306655").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/22 15:43
-	3	("5360758").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/22 17:03
-	301	((side adj wall or sidewall or side-wall) adj spacer near6 nitride) and 257/\$6.ccls. and (field adj effect adj transistor or fet or mos or mos adj fet or mosfet or nmos or pmos or nmosfet or pmosfet) ("5382533").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 09:41
-	3	("5382533").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/22 17:51
-	3	("5679968").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/22 17:52
-	3	("5714413").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/22 17:53

-	0	("ep-621632\$-\$\$.did.").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/22 17:53
-	0	("ep-621632\$-\$\$.did.").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/22 17:53
-	0	rajeevakumar.in. and dram adj cell adj structure	EPO	2002/05/22 17:55
-	6	rajeevakumar.in. and dram adj cell adj structure	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/22 17:55
-	3	("5612249").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 10:42
-	0	earom and selection same transistor same dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 10:43
-	27	earom and transistor same dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 10:44
-	6	earom and transistor same dram.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 10:45
-	109394	earom.ti,ab. and dram.ti,ab. and 257/\$6.ccls. or 438/\$6.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 10:46
-	5	earom.ti,ab. and dram.ti,ab.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 10:47
-	187	selection near12 (transistor or fet or mosfet) near12 dram	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 10:49
-	44	(selection near6 (transistor or fet or mosfet) near6 dram) and (257/\$6.ccls. or 438/\$6.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 12:09
-	3	("5854500").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 12:14
-	2	("6037639").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 13:57
-	1962	(257/296).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 12:26

-	1041	(257/401).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 15:08
-	432	(257/410).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/23 15:08
-	2	("5885553").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/06 10:35
-	2	("5612249").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/06 12:04
-	0	(side adj wall or sidewall) near12 gate adj oxide near12 silicon adj nitride adj spacer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/06 12:06
-	15	(side adj wall or sidewall) near12 gate adj oxide near12 silicon adj nitride	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/06 12:07
-	147	oxidation adj barrier near4 oxide	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/06 13:06
-	201	(MOS or MOSFET).ti,ab,clm. and silicon adj nitride near4 (sidewall or side adj wall) near4 spacer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/06 13:09
-	3702	((257/296) or (257/401) or (257/410)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/06 16:38
-	0	((((257/296) or (257/401) or (257/410)).CCLS.) and "bird's beak" near4 gate near4 underneath and silicon adj nitride	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/06 16:39
-	2	("5612249").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 14:10
-	259	oxide near2 spacer near6 nitride and (mosfet or mos adj device or field adj effect adj transistor).ti,ab,clm.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/04/15 14:15
-	6	885553.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/08 10:23
-	2	("5612249").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/08 10:24

-	2	("5907777").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/08 11:43
-	4300	((257/296) or (257/401) or (257/410)).CCLS.	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/08 11:44
-	8	((257/296) or (257/401) or (257/410)).CCLS.) and "bird's beak"	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/08 11:44
-	6	885553.ap.	USPÄT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 16:40
-	30	(US-5854500-\$ or US-5880496-\$ or US-5969382-\$ or US-6121651-\$ or US-4610078-\$ or US-5473179-\$ or US-5939761-\$ or US-6025215-\$ or US-5907777-\$ or US-5923965-\$ or US-6114735-\$ or US-6127710-\$ or US-5637514-\$ or US-5306655-\$ or US-5360758-\$ or US-6015736-\$ or US-5798550-\$ or US-5612249-\$ or US-6281079-\$ or US-6180978-\$ or US-6037639-\$ or US-5929492-\$ or US-5382533-\$ or US-5714413-\$ or US-5679968-\$ or US-5706164-\$).did. or (US-20030042551-\$ or US-20010041398-\$ or US-20010033006-\$).did. or (JP-05129595-\$).did.	USPÄT; US-PGPUB; JPO	2004/09/13 16:52
-	3	((US-5854500-\$ or US-5880496-\$ or US-5969382-\$ or US-6121651-\$ or US-4610078-\$ or US-5473179-\$ or US-5939761-\$ or US-6025215-\$ or US-5907777-\$ or US-5923965-\$ or US-6114735-\$ or US-6127710-\$ or US-5637514-\$ or US-5306655-\$ or US-5360758-\$ or US-6015736-\$ or US-5798550-\$ or US-5612249-\$ or US-6281079-\$ or US-6180978-\$ or US-6037639-\$ or US-5929492-\$ or US-5382533-\$ or US-5714413-\$ or US-5679968-\$ or US-5706164-\$).did. or (US-20030042551-\$ or US-20010041398-\$ or US-20010033006-\$).did. or (JP-05129595-\$).did.) and ahmad.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/13 16:52
-	6	272968.ap.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/14 17:56
-	1		USPAT	2004/09/14 16:48